

TECHNICAL DATA DATA SHEET 256, REV. B

HERMETIC POWER SCHOTTKY RECTIFIER 200°C Maximum Operation Temperature

DESCRIPTION: 100 VOLT, 60 AMP, DUAL HERMETIC POWER SCHOTTKY RECTIFIERS IN A SHD-5/5A PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_J = 25$ °C UNLESS OTHERWISE SPECIFIED.

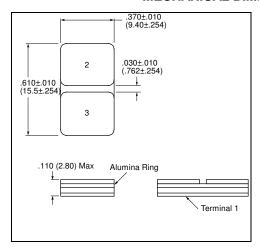
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T _C =100 ^O C)	Io	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=10ms, Sine)	I _{FSM}	700	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	1500	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R\theta_{JC}$	0.35	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to +200	°C

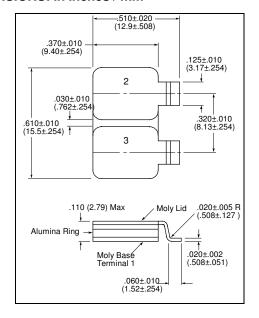
ELECTRICAL CHARACTERISTICS

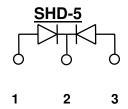
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (per leg, $I_f = 60$ Amps	5)		
T _J = 25 °C	V_{f}	0.87	Volts
T _J = 125 °C		0.72	
MAXIMUM REVERSE CURRENT (per leg, I _r @ 100 V PIV)			
T _J = 25 °C	l _r	0.5	mA
T _{.I} = 125 °C		3.0	

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MECHANICAL DIMENSIONS: In Inches / mm





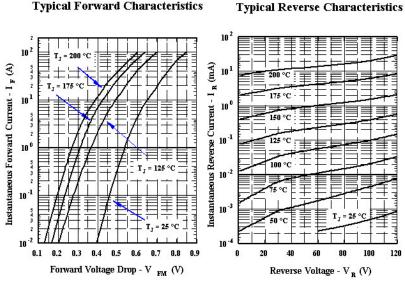


SHD-5A

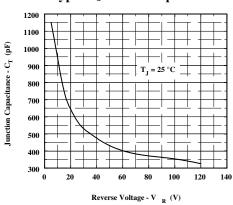
PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	COMMON CATHODE	ANODE	ANODE

Typical Forward Characteristics



Typical Junction Capacitance





TECHNICAL DATA

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